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Docket No.: 384848001US

(PATENT)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Plant Application of:

Jack Z. Peng

Application No.: 09/955,641

Art Unit: 2824

Filed: September 18, 2001

Examiner: H. N. Nguyen

For: SEMICONDUCTOR MEMORY CELL AND

MEMORY ARRAY USING A BREAKDOWN

PHENOMENA IN AN ULTRA-THIN DIELECTRIC

## AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## INTRODUCTORY COMMENTS

In response to the Office Action dated May 6, 2004, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.